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OTHER PRIOR ART (Including Author, Title, Date, Pertinent Pages, Etc.)									
A	ΑP	Favrat, Pierre et al., "A High-Efficiency CMOS Voltage Doubler", IEEE Journal of Solid-State Circuits, Vol. 33, No. 3, March 1998, pp. 410-416.							
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EXAMINER BATE CONSIDERED 8/07/2005									
* EXAMPNER: Initial if reference considered, whether or not criteria is in conformance with MPEP 609. Draw line through citation if not in conformance and not considered. Include copy of this form with next communication to applicant(s).									